

### GENERAL DESCRIPTION

The SGM40675A is an over-voltage protector with a complete set of protection functions. In low-voltage system applications, the OUT terminal can effectively prevent power supply failures up to 28V. Moreover, there is an internal clamping design that protects the product from surge events of up to  $\pm 100V$ . The SGM40675A incorporates a  $25m\Omega$  low  $R_{ON}$  N-MOSFET to facilitate efficient current flow from IN to OUT.

Whenever the input voltage is higher than the over-voltage threshold, the internal MOSFETs are automatically shut down to prevent over-voltage from causing harm to downstream devices. The two OVP threshold voltages (12.9V/23V) can be programmed through VP pin. The over-voltage protection function can ensure the safe operation of surge events in any state. Additionally, it supports reverse bias blocking, when the device is turned off, the reverse protection function is activated. This function effectively prevents any voltage flowing from the OUT pin to the IN pin.

To further enhance protection, the SGM40675A has improved ESD and thermal protection function against overload conditions.

The SGM40675A is available in a Green WLCSP-2.27 $\times$ 1.86-20B package.

### FEATURES

- **Input Voltage Range: 3V to 24V with Surge up to  $\pm 100V$**
- **On-Resistance: 25m $\Omega$  (TYP)**
- **Continuous Current: 5A**
- **Over-Voltage Threshold**
  - ◆ 12.9V: Leave VP Floating
  - ◆ 23V: Connect VP to GND
- **VSNS Pin: Fixed 5V Output**
- **Fast Over-Voltage Response: 100ns**
- **Input Quiescent Current: 130 $\mu A$  (TYP)**
- **Full Set of Protections**
  - ◆ Soft-Start
  - ◆ Under-Voltage Protection
  - ◆ Thermal Shutdown
  - ◆ Reverse Blocking (OUT to IN)
- **VSNS, nEN, nWRX, and nFLAG Pins**
- **Available in a Green WLCSP-2.27 $\times$ 1.86-20B Package**

### APPLICATIONS

- Tablet
- Smart Phone
- Mobile Internet Device
- Peripheral

### TYPICAL APPLICATION

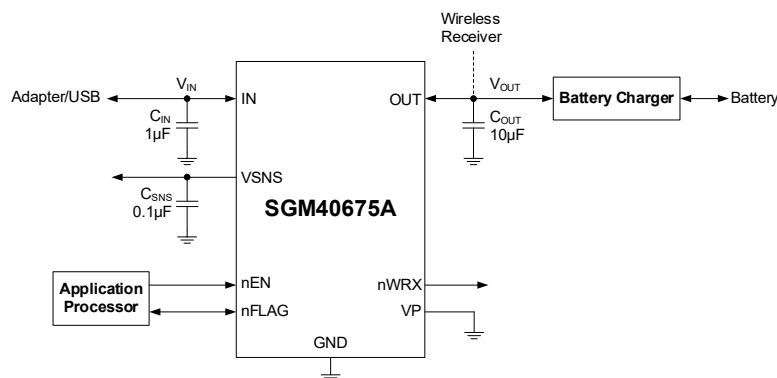


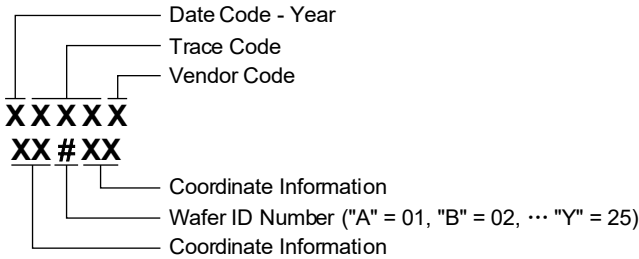
Figure 1. Typical Application Circuit

**PACKAGE/ORDERING INFORMATION**

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM40675A	WLCSP-2.27×1.86-20B	-40°C to +125°C	SGM40675AXG/TR	SGM05G XXXXX XX#XX	Tape and Reel, 3000

**MARKING INFORMATION**

NOTE: XXXXX = Date Code, Trace Code and Vendor Code. XX#XX = Coordinate Information and Wafer ID Number.



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

**ABSOLUTE MAXIMUM RATINGS**

- IN Voltage Range..... -0.3V to 28V
- OUT Voltage Range..... -0.3V to 26V
- IN to OUT Voltage (When Off) ..... -26V to 28V
- nEN, nFLAG and nWRX Pins ..... -0.3V to 6V
- VSNS Pin Voltage..... -0.3V to 6V
- Continuous Current, IN, OUT..... 5A
- Junction Temperature ..... +150°C
- Storage Temperature Range..... -65°C to +150°C
- Lead Temperature (Soldering, 10s) ..... +260°C
- ESD Susceptibility
- HBM..... 4kV
- CDM ..... 1kV
- Air Gap Discharge on IN Pin (IEC 61000-4-2)..... 15kV
- Contact Discharge on IN Pin (IEC 61000-4-2)..... 8kV

**RECOMMENDED OPERATING CONDITIONS**

- IN Voltage Range..... 3V to 24V
- OUT Voltage Range..... 3V to 24V
- Operating Ambient Temperature Range..... -40°C to +125°C
- Input Capacitance, C<sub>IN</sub>..... 10µF (MAX)
- OTG Hot Swap Capacitance, C<sub>OTG</sub>..... 200µF (MAX)
- Output Capacitance, C<sub>OUT</sub> ..... 20µF (MAX)
- VSNS Capacitance, C<sub>VSNS</sub> ..... 1µF (MAX)

**OVERSTRESS CAUTION**

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

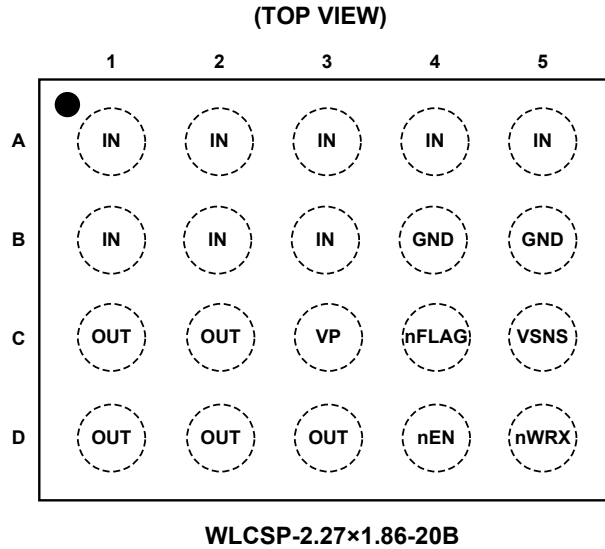
**ESD SENSITIVITY CAUTION**

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

**DISCLAIMER**

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

PIN CONFIGURATION



PIN DESCRIPTION

PIN	NAME	TYPE	FUNCTION
A1, A2, A3, A4, A5, B1, B2, B3	IN	Power	Load Switch Input Pin.
B4, B5	GND	G	Ground.
C1, C2, D1, D2, D3	OUT	Power	Load Switch Output Pin.
C3	VP	Digital Input	Programmable OVP Voltage Pin. The two OVP threshold voltages can be programmed through VP pin. Connect the pin to GND to select 23V (TYP). Float the pin to select 12.9V (TYP).
C4	nFLAG	Digital I/O	nFLAG Pin. When the system detects that OTG mode can be activated/triggered in master mode, the nFLAG pin is pulled high. Slave mode: pull this pin logic low. Master mode: to enter OTG mode, connect to the system digital I/O pin (or equivalent) and pull this pin logic low when connecting IN to the OTG load and supplying power to OUT.
C5	VSNS	Analog Output	IN Pin Voltage Indicator. The internal LDO clamps the IN to 5V and output through the VSNS pin.
D4	nEN	Digital Input	Asserting nEN Pin High Disables the Device. Slave mode: connect the nEN pin to system enable pin. Master mode: pull the nEN pin logic low or GND.
D5	nWRX	Digital I/O	Active-Low Wireless Receiver (WRx) Enable Pin. Slave mode: pull the nWRX pin logic low. Master mode: if the system output control pin is not available, connect it to WRx active-low enable pin.

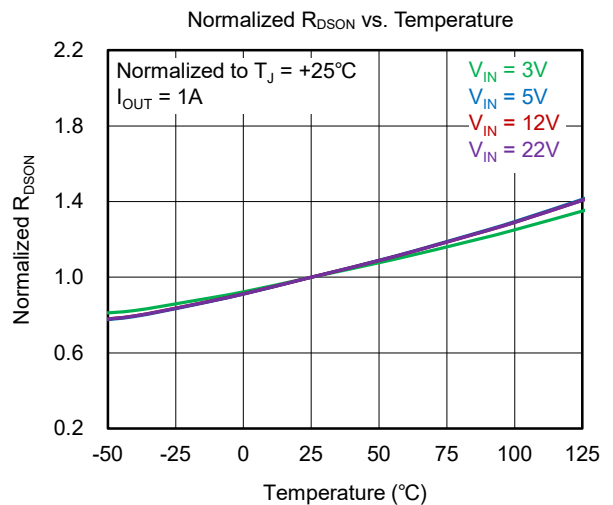
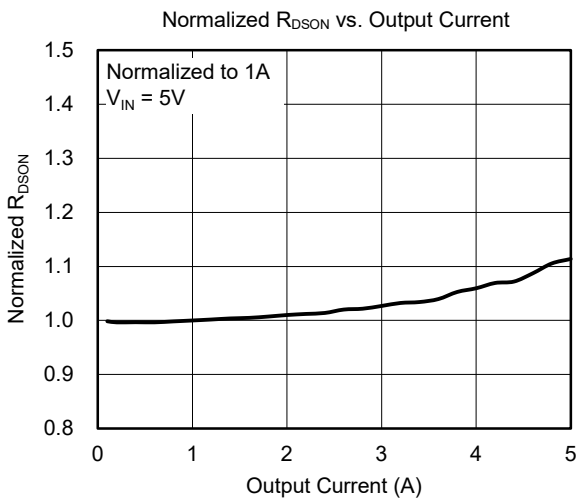
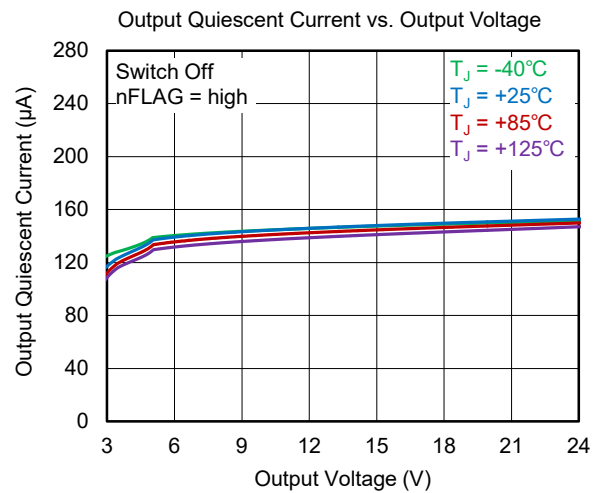
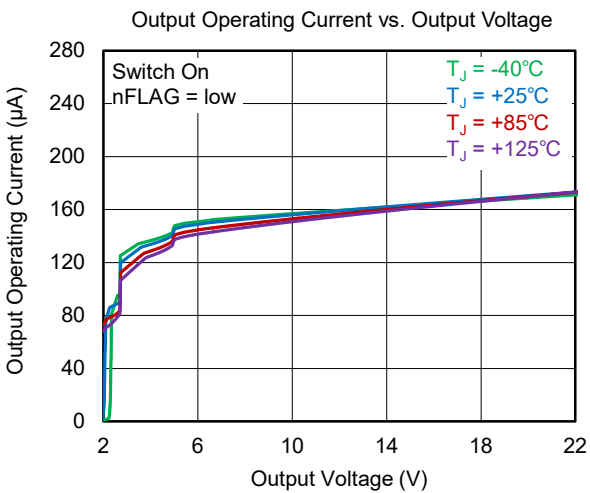
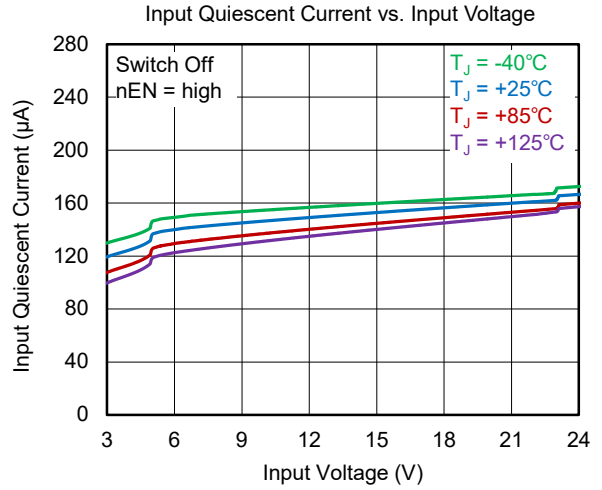
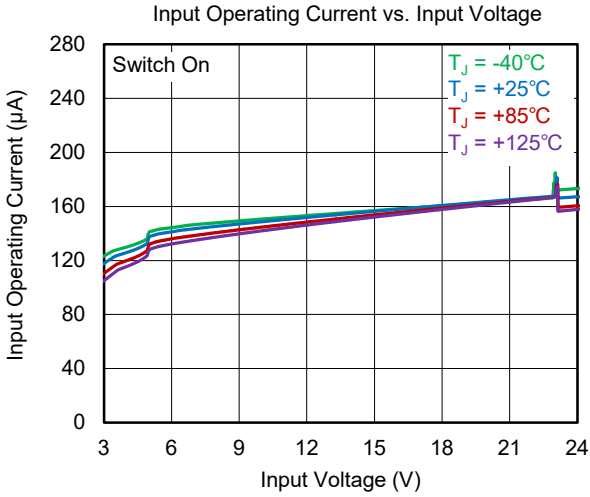
## ELECTRICAL CHARACTERISTICS

(T<sub>J</sub> = -40°C to +125°C, V<sub>IN</sub>/V<sub>OUT</sub> = 5V, typical values are specified at T<sub>J</sub> = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
<b>Input, OVP (IN to OUT)</b>							
Input Operating Supply Voltage	V <sub>IN</sub>		3		24	V	
Output Operating Supply Voltage	V <sub>OUT</sub>		3		24	V	
Input/Output UVLO Rising Threshold	V <sub>UVLO</sub>	Initiates soft-start after deglitch time	2.5	2.7	2.9	V	
UVLO Hysteresis	V <sub>UVLO_HYS</sub>	Falling V <sub>IN</sub>		0.13		V	
Continuous Output Current	I <sub>OUT</sub> , I <sub>OTG</sub>				5	A	
Input OVP Rising Threshold	V <sub>OVP</sub>	V <sub>IN</sub> > V <sub>OVP</sub> enters fault mode	VP = GND	22	23	24	V
			VP = floating,	12.3	12.9	13.5	V
OVP Hysteresis	V <sub>OVP_HYS</sub>	Falling V <sub>IN</sub>		0.5		V	
On-Resistance	R <sub>DS(on) (IN-OUT)</sub>	I <sub>IN</sub> = 1A, T <sub>J</sub> = +25°C		25	35	mΩ	
Input Quiescent Current, Standby/Fault State	I <sub>Q_IN</sub>	nEN = high		130	200	μA	
Input Operating Current	I <sub>DD_IN</sub>	nEN = low, I <sub>OUT</sub> = 0mA		130	200	μA	
Output Quiescent Current, Standby/Fault State	I <sub>Q_OUT</sub>	OTG mode, nEN = high		140	210	μA	
Output Operating Current	I <sub>DD_OUT</sub>	OTG mode, nEN = low, no load		130	200	μA	
Clamping IN Quiescent Current	I <sub>Q_IN CLAMP</sub>	V <sub>IN</sub> = 28V, V <sub>OUT</sub> = 0V		0.2	0.5	mA	
		V <sub>IN</sub> = 28V, V <sub>OUT</sub> = 6V		0.2	0.5		
OUT Discharge Resistance	R <sub>DIS</sub>	Measured from OUT to GND during discharge event, V <sub>IN</sub> = 3V		440	650	Ω	
OUT Float Voltage	V <sub>IN-OUT (Float)</sub>	Standby state, nFLAG = high and/or nEN = high, V <sub>IN</sub> = 4.5V to 16V		0.2	0.8	V	
IN Float Voltage	V <sub>OUT-IN (Float)</sub>	OTG state, nFLAG = high and/or nEN = high, V <sub>OUT</sub> = 4.5V to 16V		0.03	0.5	V	
<b>VSNS</b>							
Regulated Output	V <sub>SNS</sub>	V <sub>IN</sub> = 6V to OVP, I <sub>SNS</sub> = 0mA to 40mA	4.6	5	5.3	V	
<b>Timing Characteristics</b>							
Input Debounce Time	t <sub>DEB</sub>	V <sub>UVLO</sub> < V <sub>IN</sub> < V <sub>OVP</sub> , nEN = low, time delay between IN rising and nWRX rising.		50		ms	
Discharge Time	t <sub>DIS</sub>	Time after debounce time nWRX rising to OUT soft-start.		50		ms	
Soft-Start Time	t <sub>SST</sub>	Bidirectional IN to OUT or OUT to IN, time is from 20% to 80% of input.		0.8	1.6	ms	
Switch Turn-Off Response Time	t <sub>OVP_DLY</sub>	V <sub>IN</sub> > V <sub>OVP</sub> to V <sub>OUT</sub> stop rising		100		ns	
Logic Pin Enable Delay (nEN, nFLAG)	t <sub>DELAY</sub>	Time delay from nEN, nFLAG enable/disable load switch, excluding soft-start		200		μs	
<b>Digital Signals</b>							
Digital Logic Thresholds (nEN, nFLAG, nWRX)	V <sub>IL</sub>	Input logic low			0.4	V	
	V <sub>IH</sub>	Input logic high	0.7			V	
Output Voltage (nFLAG, nWRX)	V <sub>OL</sub>	Output logic low, sinking = 1mA		0.08	0.15	V	
	V <sub>OH</sub>	Output logic high, no load	3	3.25	3.5	V	
nFLAG Pull-Up Resistance	R <sub>OH_nFLAG</sub>			400		kΩ	
nWRX Pull-Up Resistance	R <sub>OH_nWRX</sub>			200		kΩ	
nEN Pull-Down Resistor	R <sub>nEN</sub>			400		kΩ	
<b>Thermal Shutdown</b>							
Thermal Shutdown Threshold	T <sub>SD</sub>			150		°C	
Thermal Shutdown Hysteresis	T <sub>HYS</sub>			25		°C	

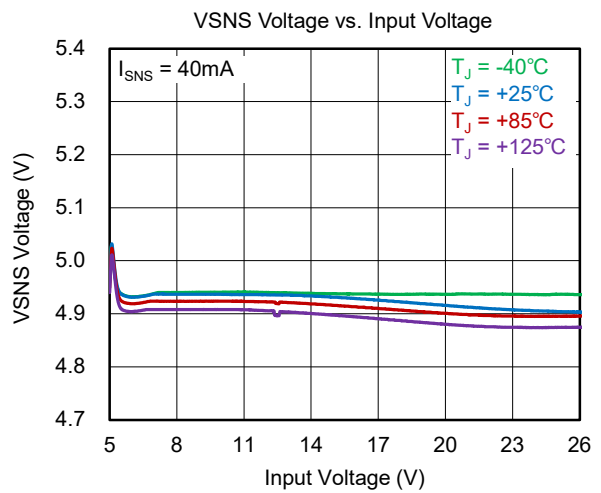
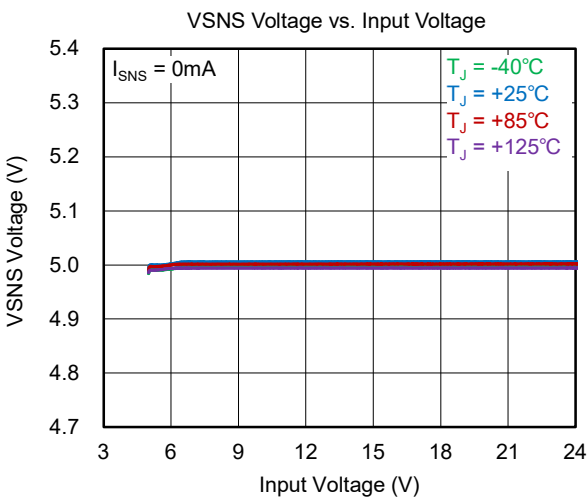
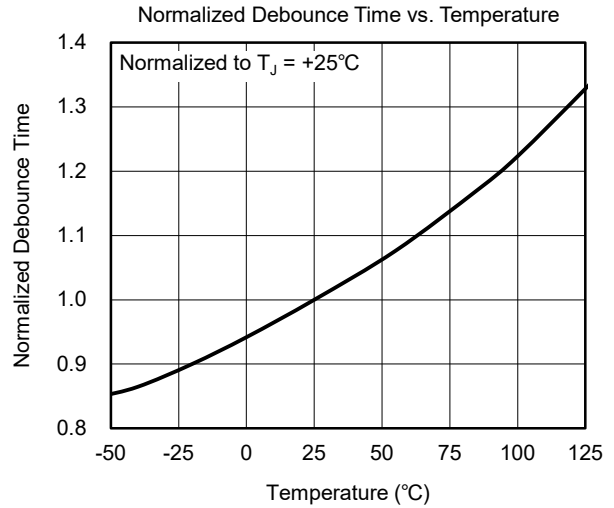
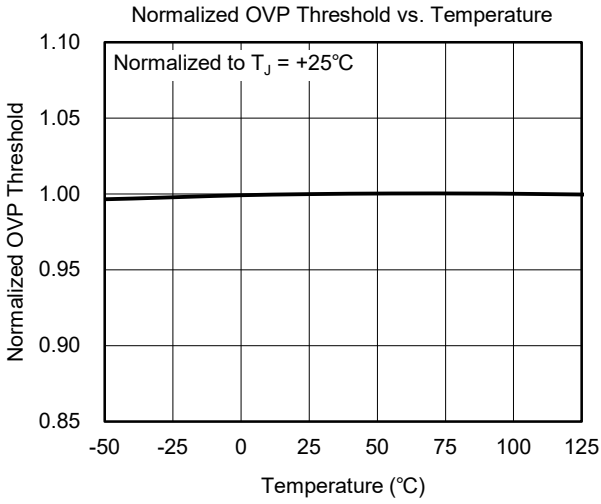
TYPICAL PERFORMANCE CHARACTERISTICS

$V_{IN}/V_{OUT} = 5V$ ,  $C_{IN} = 1\mu F$ ,  $C_{OUT} = 10\mu F$ ,  $T_J = +25^\circ C$ , nWRX floating (high), nFLAG floating (high), nEN floating (low), VP = GND ( $V_{OVP} = 23V$ ), unless otherwise specified.



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

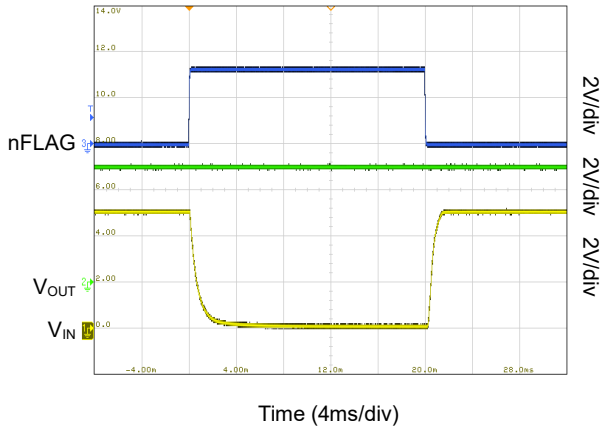
$V_{IN}/V_{OUT} = 5V$ ,  $C_{IN} = 1\mu F$ ,  $C_{OUT} = 10\mu F$ ,  $T_J = +25^\circ C$ , nWRX floating (high), nFLAG floating (high), nEN floating (low), VP = GND ( $V_{OVP} = 23V$ ), unless otherwise specified.



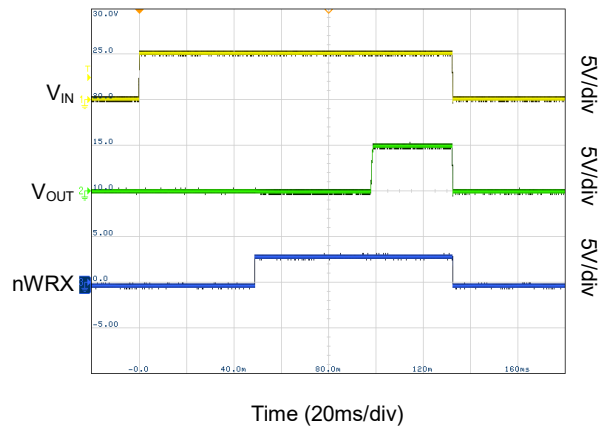
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

$V_{IN}/V_{OUT} = 5V$ ,  $C_{IN} = 1\mu F$ ,  $C_{OUT} = 10\mu F$ ,  $T_J = +25^\circ C$ , nWRX floating (high), nFLAG floating (high), nEN floating (low), VP = GND ( $V_{OVP} = 23V$ ), unless otherwise specified.

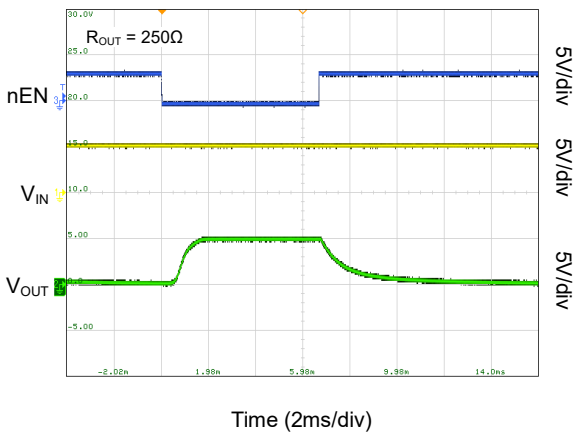
OTG Mode nFLAG Turn On-Off



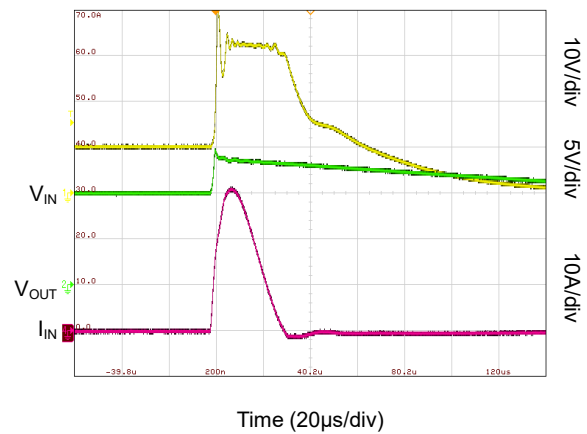
VIN 5V Insert-Remove



Turn On-Off with nEN  
(Slave Mode nWRX = nFLAG = Low)



Surge Transient (100V)



FUNCTIONAL BLOCK DIAGRAM

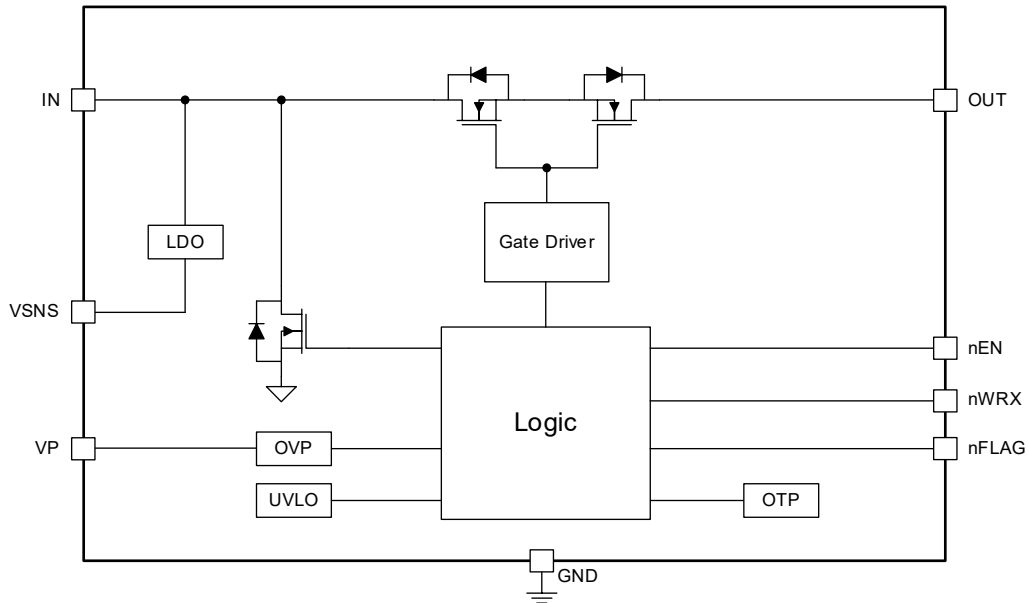


Figure 2. SGM40675A Block Diagram



DETAILED DESCRIPTION

The SGM40675A is used for load protection to connect power/charger source. Two back-to-back low impedance power NMOS switches are integrated. SGM40675A contains functions such as over-voltage detection, under-voltage protection, and power good indication.

The over-voltage protection function can protect device input voltage from rising faults up to +28V<sub>DC</sub>. The internal TVS can provide +100V surge protection for the device. The internal power MOSFETs are turned off when the input voltage reaches the OVP value. A debounce time of 50ms is set before the output starts up to prevent false turn-on of the power MOSFETs. OTG mode allows the device to be bi-conductive. When OTG mode is disabled, the device's IN pin blocks any voltage from OUT pin.

The OVP value can be selected by controlling the state of the VP pin. Grounding VP pin selects the 23V OVP value. Leave the VP pin floating turns the OVP value to typically 12.9V.

Dual Input Device Operation

The SGM40675A load switch can be equivalent to a 2:1 power multiplexer by adding a wireless Rx (WRx), as shown in Figure 3. When disabled, please make sure the wireless receiver withstand voltage value is greater than or equal to 24V, which is also the maximum operating voltage of the SGM40675A.

By controlling the input state (IN adapter and/or nWRx) can implement the mode transition between off and OTG. OTG plug-in event triggers mode transition into OTG mode.

Operation Modes

The SGM40675A can operate in master or slave modes. The device assigns input priority to the IN power over the wireless receiver in master mode, while allows an external system (battery charger) to act as a master to determine input priority in slave mode.

Both master mode and slave mode contains a 50ms deglitch period and 0.8ms soft-start time.

Grounding the nWRX pin to enter the slave mode can cancel a 50ms automatic break-before-make discharge period that included in the master mode.

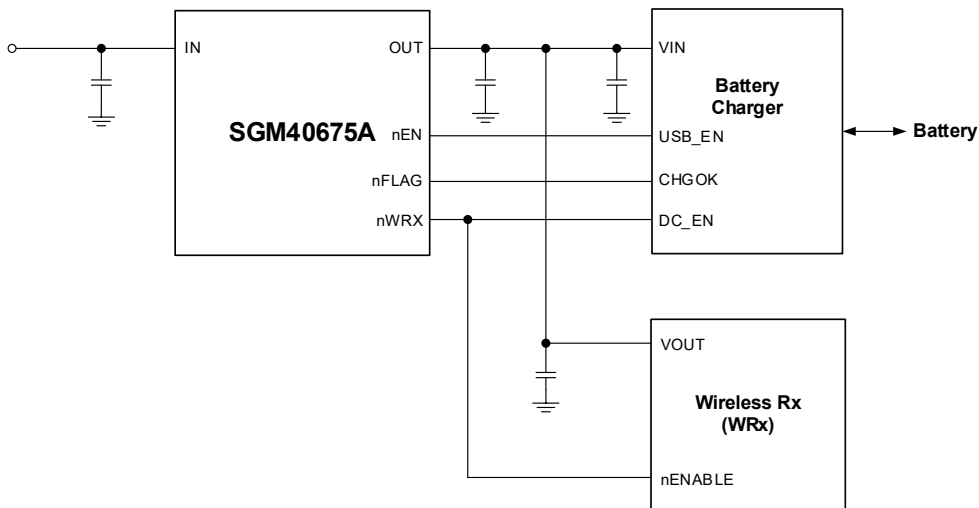


Figure 3. Dual Input Device Operation

DETAILED DESCRIPTION (continued)

Master Mode

In master mode, after a valid input voltage is appeared and the nEN pin is grounded, the load switch controller will turn on the power FETs after a fixed delay. IN pin has the input priority in master mode.

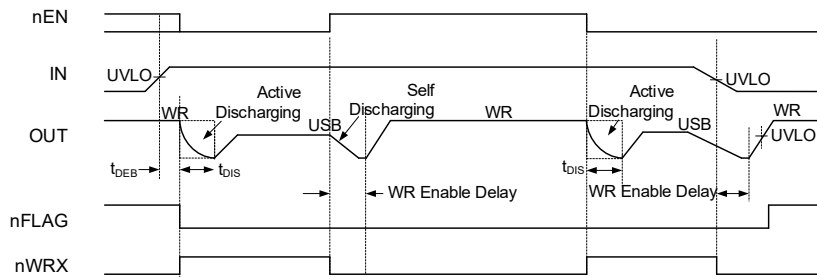
Charging (IN to OUT):

- The load switch assigns the input/wireless priority.
- The IN pin is connected to a valid voltage source.
- Grounding nEN to turn on the load switch and allow the current to flow from IN to OUT.
- Grounding nEN to pull nWRX high to shut down the wireless receiver.
- When OTG event occurs, nFLAG become high. (OUT is connected to a valid voltage source and IN is lower than UVLO.)

OTG (OUT to IN):

- The OUT pin is connected with a valid voltage source, and IN voltage is lower than UVLO.
- OTG event triggers nFLAG pulled high.
- Both nEN and nFLAG are pulled low to turn on the load switch and allow current flowing from OUT to IN.
- Grounding the nFLAG and nEN pins to trigger the nWRX pulled high to shut down the wireless receiver.

Before  $t_{DEB}$  expires, nEN is pulled to low:



After  $t_{DEB}$  expires, nEN is pulled to low:

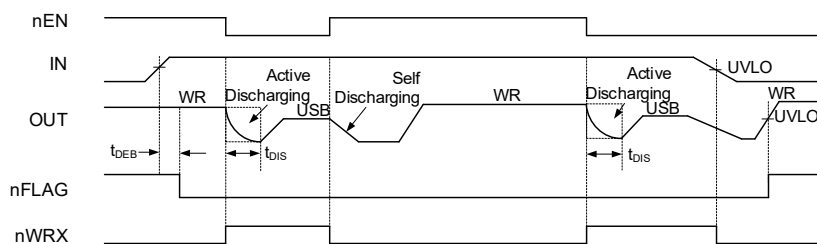


Figure 4. Master Mode Charging

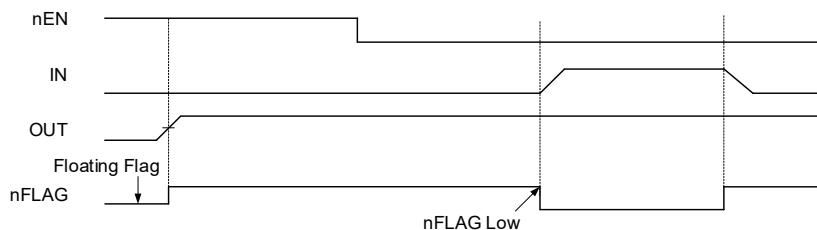


Figure 5. Master Mode OTG

DETAILED DESCRIPTION (continued)

Slave Mode

The external system (battery charger) works as master to enable load switch on-state through nEN pin. In this mode, both nFLAG and nWRX can tie to GND and the system (charger) assigns the input priority.

- ◆ Before charging through SGM40675A, the charger will shut down the wireless receiver.
- ◆ Grounding nEN to turn on the load switch and allow the current flowing from IN to OUT.

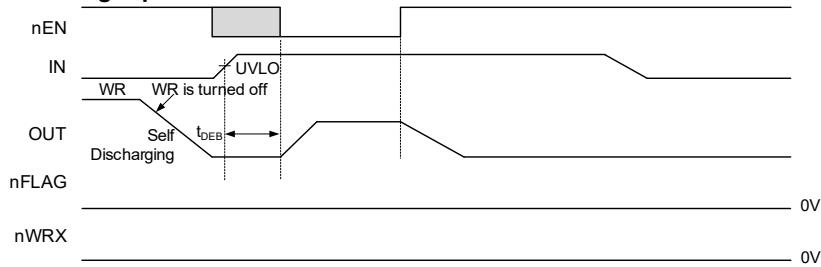
Charging (IN to OUT):

- ◆ The IN pin is connected to a valid voltage source.

OTG (OUT to IN):

- ◆ Once OUT is connected to a valid voltage source, nEN is grounded by charger to allow the current flowing from OUT to IN.

Before the  $t_{DEB}$  expires, the charger pulls nEN to a low level:



After  $t_{DEB}$  expires, the charger pulls nEN to a low level:

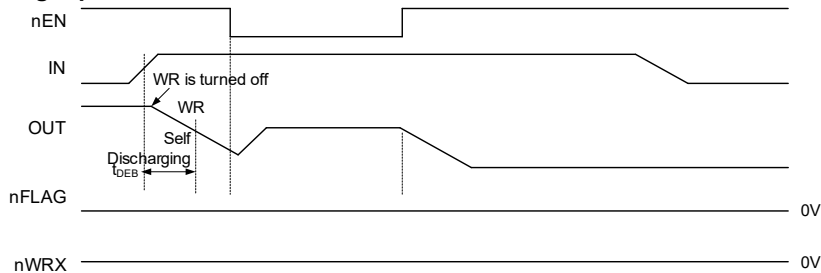
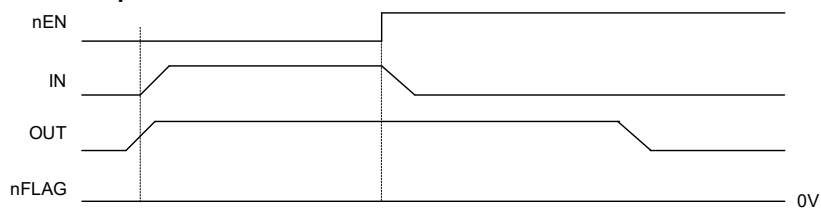


Figure 6. Slave Mode Charging

Before  $V_{OUT}$  ramps up, the nEN is pulled to a low level:



After  $V_{OUT}$  ramps up, nEN is pulled to a low level:

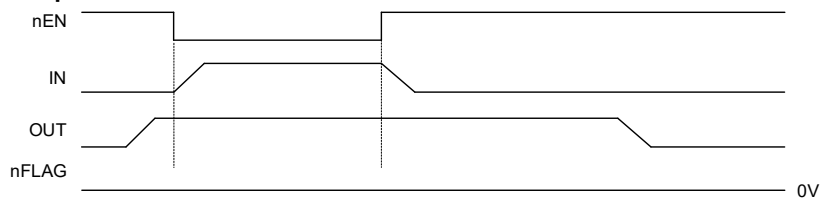


Figure 7. Slave Mode OTG

DETAILED DESCRIPTION (continued)

Input Surge Protection

The IN pin to GND pin of the device must withstand a +100V surge regardless the state of the load switch is on or off. The device's surge protection meets the requirements of the IEC 61000-4-5 specification,  $R_{SOURCE} = 2.0\Omega$ , 1.2/50 $\mu$ s waveform.

Over-Voltage Protection

The load switch instantly turns off when input voltage is greater than the programmed OVP value. This function protects the device and downstream components from being damaged.

The OVP threshold value can be programmed by the state of the VP pin. Grounding the VP pin gets a typical 23V OVP threshold value and floating this pin turns the OVP threshold value to typical 12.9V.

Soft-Start

The function of soft-start minimizes the inrush current during the load switch enable duration either in master mode or slave mode.

OTG

An OTG plug-in event triggers the OTG mode, about 5V power source is connected to the OUT pin and an OTG load is connected to the IN pin.

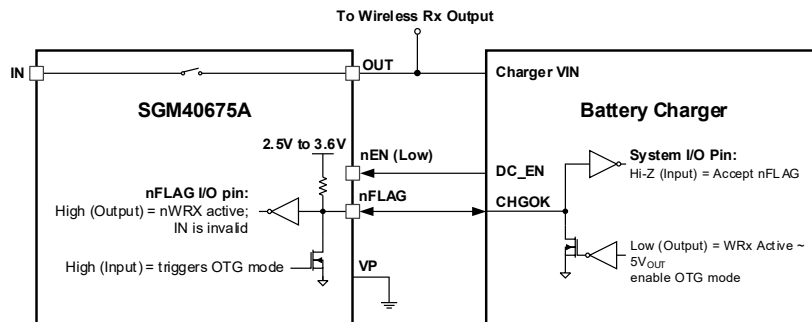
Bidirectional Blocking

The SGM40675A integrates the bidirectional blocking function that will block any reverse current. When input voltage is less than the input start-up voltage or greater than the OVP threshold value and the nFLAG pin is pulled high (OTG mode is disabled), the FETs between IN and OUT are turned off and the internal body diodes are back-to-back.

nFLAG Logic

The OTG mode can be enabled or disabled by controlling the state of the nFLAG pin in master mode.

When a valid OUT voltage is applied and the IN pin is disconnected from the power source, the nFLAG pin works as an output indication pin and is tied to high. Grounding the nFLAG pin triggers the OTG mode on.



IN	OUT	nFLAG	CHGOK	Load Switch Behavior (nEN = Low)
< UVLO	> UVLO	High	Hi-Z	If the load switch is off, and the OTG mode can be enabled. The battery charger determines the on/off state of WRx.
= V <sub>OUT</sub>	= V <sub>OUT</sub>	Low	Low	If the load switch is on, and the OTG mode is enabled. The battery charger determines the on/off state of WRx.
> UVLO	Low	Low	X	Load switch is off (nEN is pulled to high), and OTG mode is not allowed.

Figure 8. nFLAG Logic

DETAILED DESCRIPTION (continued)

**Input Capacitor**

It recommends 1μF or larger capacitor used as C<sub>IN</sub>. Besides, please locate C<sub>IN</sub> closely to device. The 50V rated ceramic capacitors are suitable for the OVP situation of the device and withstand most surges.

**Output Capacitor**

The soft-start function can reduce the inrush current by slowly turning on the load switch. It is recommended to use a 1μF or larger ceramic capacitor as the output capacitor.

**VSNS Indication**

VSNS pin is regulated to 5V typical and can support about 40mA to external loads. The VSNS sets up once I<sub>N</sub> is greater than UVLO. OTP event can disable the VSNS output. Large voltage drop between I<sub>N</sub> and VSNS can also cause the large power consumption when over-current protection is not triggered, so please try to avoid this situation.

Please refer to timing diagram below for more details of VSNS's behavior.

**VSNS Capacitor**

It is recommended that 0.1μF or larger capacitor be used for bypass VSNS.

**Thermal Protection**

The SGM40675A integrates over-temperature protection, and the device turns off the power FETs if the junction temperature exceeds +150°C (TYP), and the recovery value is about +125°C (TYP).

**ESD Test Conditions and HBM ESD Protection**

The SGM40675A meets the requirement of IEC61000-4-2 standard (1μF used as input capacitor on board). I<sub>N</sub> integrates a protection feature that can tolerate ±15kV<sub>ESD</sub> in air condition. V<sub>IN</sub> can withstand ±8kV<sub>ESD</sub> in contact condition and air-gap condition.

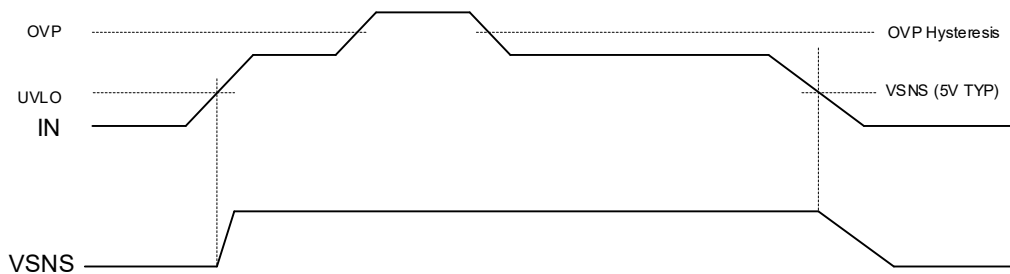


Figure 9. Timing Diagram for VSNS

REVISION HISTORY

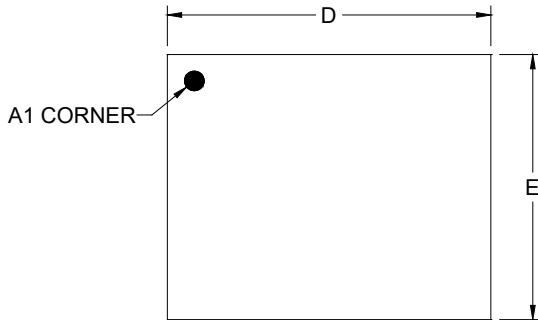
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original (NOVEMBER 2023) to REV.A	Page
Changed from product preview to production data.....	All

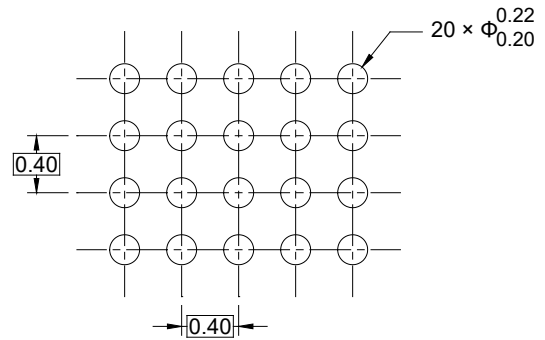
# PACKAGE INFORMATION

## PACKAGE OUTLINE DIMENSIONS

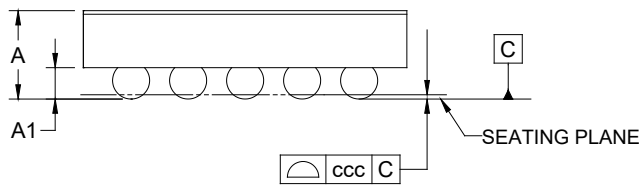
### WLCSP-2.27×1.86-20B



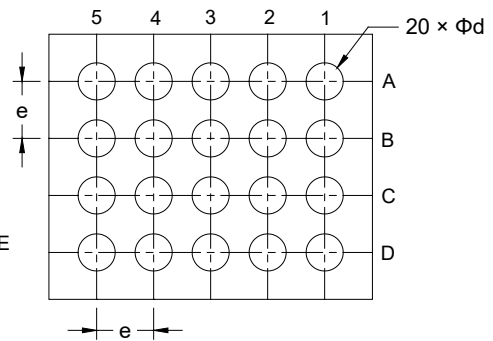
TOP VIEW



RECOMMENDED LAND PATTERN (Unit: mm)



SIDE VIEW



BOTTOM VIEW

Symbol	Dimensions In Millimeters		
	MIN	MOD	MAX
A	-	-	0.665
A1	0.200	-	0.240
D	2.240	-	2.300
E	1.832	-	1.892
d	0.230	-	0.290
e	0.400 BSC		
ccc	0.050		

NOTE: This drawing is subject to change without notice.

# PACKAGE INFORMATION

## TAPE AND REEL INFORMATION

### REEL DIMENSIONS



### TAPE DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

### KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
WLCSP-2.27×1.86-20B	7"	9.5	2.01	2.42	0.78	4.0	4.0	2.0	8.0	Q2

000001

# PACKAGE INFORMATION

## CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

## KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18

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